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1N5819HW

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1.0A SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Product Summary (@ TA = +25°C)

V _{RRM} (V)	I _O (A)	V _{F(MAX)} (mV)	I _{R(MAX)} (μ A)
40	1.0	450	50

Description and Applications

- For Use in Low Voltage, High Frequency Inverters
- Free Wheeling
- Polarity Protection Application

Features and Benefits

- High Surge Capability
- Low Power Loss, High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Guard Ring Die Construction for Transient Protection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Notes 3)

Mechanical Data

- Case: SOD123
- Plastic Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Polarity: Cathode Band
- Leads: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.01 grams (approximate)



Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
1N5819HW-7-F	SOD-123	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant
- 2.. See http://www.diodes.com/quality/lead_free.htmlfor more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



SL = Product Type Marking Code YM = Date Code Marking Y = Year (ex: B = 2014) M = Month (ex: 9 = September)

Date Code Key

Year	201	1	2012		2013	20	14	2015		2016	2	2017
Code	Υ		Z		Α	E	3	С		D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic		Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	@ I _R = 1.0mA	V _{RRM} V _{RWM} V _R	40	V
RMS Reverse Voltage		V _{R(RMS)}	28	V
Average Rectified Output Current	@ T _L = +90°C	I ₀	1.0	Α
Repetitive Peak Forward Current $t_{p \le 1} \text{Ims}, \delta \le 0.5$		I _{FRM}	1.5	А
Non-Repetitive Peak Forward Surge Current Single Half Sine-Wave Superimposed on Ra	I _{FSM}	25	А	

Thermal Characteristics

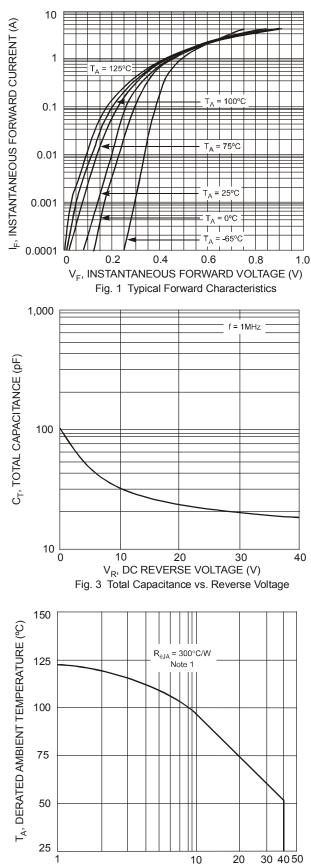
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P_{D}	450	mW
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{ hetaJA}$	222	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-65 to +125	°C

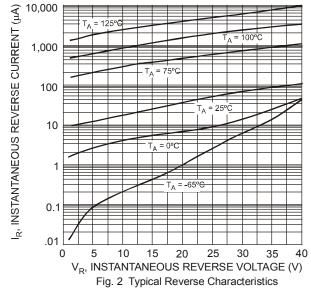
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

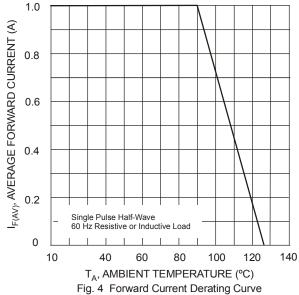
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 3)	$V_{(BR)R}$	40			>	I _R = 1.0mA
Forward Voltage	V _F			0.320 0.450 0.750	>	I _F = 0.1A I _F = 1.0A I _F = 3.0A
Reverse Leakage Current (Note 6)	I _R		 10 1 15 1.5	1.0 10 50 2 75 3	mA μA mA μA	$V_R = 40V, T_A = +25^{\circ}C$ $V_R = 40V, T_A = +100^{\circ}C$ $V_R = 4V, T_A = +25^{\circ}C$ $V_R = 4V, T_A = +100^{\circ}C$ $V_R = 6V, T_A = +25^{\circ}C$ $V_R = 6V, T_A = +100^{\circ}C$
Total Capacitance	C _T	_	50	60	pF	V _R = 4V, f = 1.0MHz

 Device mounted on FR-4 PC Board, 2"x2", 2 oz. Copper, single sided, Cathode pad dimensions 0.75"x1.0", Anode pad dimensions 0.25"x1.0".
 Short duration pulse test used to minimize self-heating effect. Notes:









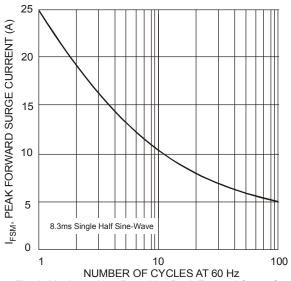


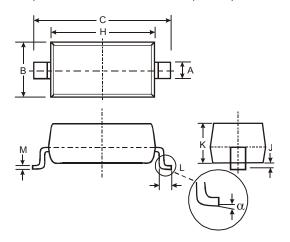
Fig. 6 Maximum Non-Repetitive Peak Forward Surge Current

 V_R , DC REVERSE VOLTAGE (V) Fig. 5 Operating Temperature Derating



Package Outline Dimensions

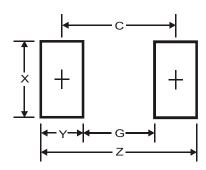
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOD123					
Dim	Min Max				
Α	0.55 Typ				
В	1.40	1.70			
C	3.55	3.85			
Н	2.55	2.85			
J	0.00 0.10				
K	1.00 1.35				
٦	0.25 0.40				
М	0.10	0.15			
α	0	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	4.9
G	2.5
Х	0.7
Υ	1.2
С	3.7



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